# **Darlington Transistor**

## **NPN Silicon**

### Features

• Pb–Free Packages are Available\*

### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V <sub>CES</sub>	60	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	10	Vdc
Collector Current – Continuous	Ι <sub>C</sub>	500	mAdc
Total Device Dissipation @ $T_A = 25^{\circ}C$ Derate above 25°C	PD	625 5.0	mW mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

### THERMAL CHARACTERISTICS

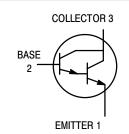
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\thetaJA}$	200	°C/W

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

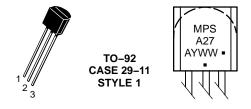


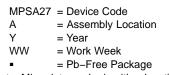
### **ON Semiconductor®**

http://onsemi.com









(Note: Microdot may be in either location)

### **ORDERING INFORMATION**

	<b>_</b> .	<b>e</b>
Device	Package	Shipping <sup>†</sup>
MPSA27	TO-92	5000 Units/Box
MPSA27G	TO–92 (Pb–Free)	5000 Units/Box
MPSA27RLRA	TO-92	2000/Tape & Reel
MPSA27RLRAG	TO-92 (Pb-Free)	2000/Tape & Reel
MPSA27RLRM	TO-92	2000/Ammo Pack
MPSA27RLRMG	TO-92 (Pb-Free)	2000/Ammo Pack

+For information on tape and reel specifications, including part orientation and tape sizes, please

refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### MPSA27

# **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = $25^{\circ}$ C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS				1	
Collector – Emitter Breakdown Voltage $(I_C = 100 \ \mu Adc, \ V_{BE} = 0)$	V <sub>(BR)CES</sub>	60	_	_	Vdc
Collector – Base Breakdown Voltage $(I_C = 100 \ \mu Adc, I_E = 0)$	V <sub>(BR)CBO</sub>	60	_	-	Vdc
Collector Cutoff Current $(V_{CB} = 30 \text{ V}, I_E = 0)$ $(V_{CB} = 40 \text{ V}, I_E = 0)$ $(V_{CB} = 50 \text{ V}, I_E = 0)$	І <sub>СВО</sub>	-	-	100	nAdc
Collector Cutoff Current $(V_{CE} = 30 \text{ V}, V_{BE} = 0)$ $(V_{CE} = 40 \text{ V}, V_{BE} = 0)$ $(V_{CE} = 50 \text{ V}, V_{BE} = 0)$	ICES	-	-	500	nAdc
Emitter Cutoff Current (V <sub>EB</sub> = 10 Vdc)	I <sub>EBO</sub>	-	_	100	nAdc
ON CHARACTERISTICS (Note 1)				•	
DC Current Gain (I <sub>C</sub> = 10 mA, V <sub>CE</sub> = 5.0 V) (I <sub>C</sub> = 100 mA, V <sub>CE</sub> = 5.0 V)	h <sub>FE</sub>	10,000 10,000			-
Collector – Emitter Saturation Voltage $(I_C = 100 \text{ mA}, I_B = 0.1 \text{ mAdc})$	V <sub>CE(sat)</sub>	-	_	1.5	Vdc
Base – Emitter On Voltage (I <sub>C</sub> = 100 mA, V <sub>CE</sub> = 5.0 Vdc)	V <sub>BE(on)</sub>	-	_	2.0	Vdc
SMALL-SIGNAL CHARACTERISTICS	·	•	-	•	
Small Signal Current Gain ( $I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}, f = 100 \text{ MHz}$ )	h <sub>fe</sub>	1.25	2.4	-	-
Pulse Test: Pulse Width < 300 us. Duty Cycle < 2.0%	•			•	•

1. Pulse Test: Pulse Width  $\leq$  300  $\mu s,$  Duty Cycle  $\leq$  2.0%.

MPSA27

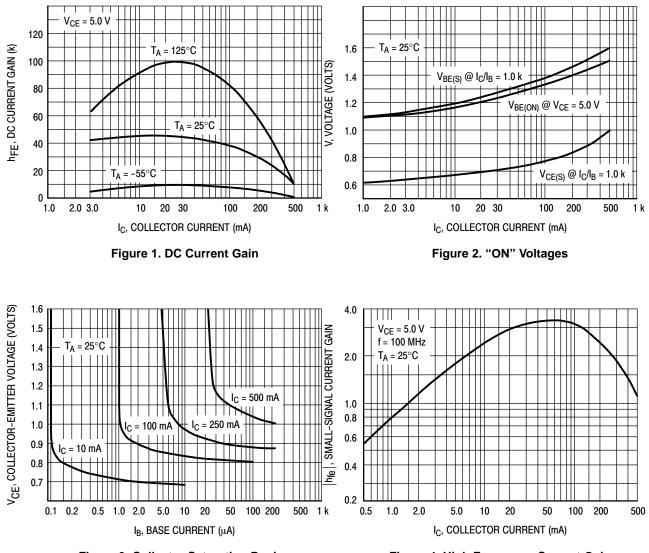


Figure 3. Collector Saturation Region

Figure 4. High Frequency Current Gain

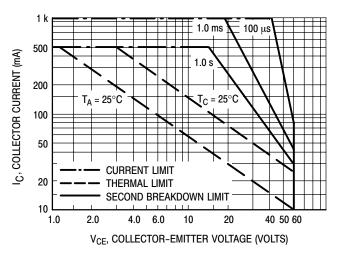
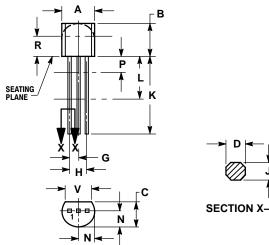


Figure 5. Active Region – Safe Operating Area

### MPSA27

### PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 **ISSUE AL** 







NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI 1. Y14.5M, 1982.
- 2
- TI4-3M, 1962. CONTROLLING DIMENSION: INCH. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED. LEAD DIMENSION IS UNCONTROLLED IN P AND 3.
- 4. BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	ETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.20	
В	0.170	0.210	4.32	5.33	
С	0.125	0.165	3.18	4.19	
D	0.016	0.021	0.407	0.533	
G	0.045	0.055	1.15	1.39	
Η	0.095	0.105	2.42	2.66	
L	0.015	0.020	0.39	0.50	
Κ	0.500		12.70		
Г	0.250		6.35		
Ν	0.080	0.105	2.04	2.66	
Ρ		0.100		2.54	
R	0.115		2.93		
۷	0.135		3.43		

STYLE 1: PIN 1. EMITTER

BASE 2. 3.

COLLECTOR

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